élantec
HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

EL2244C, EL2444C

Dual/Quad Low-Power 120MHz Unity-Gain Stable Op Amp

Features

- 120MHz gain-bandwidth product
- Unity-gain stable
- Low supply current (per amplifier) - 5.2mA at V_S = ±15V
- Wide supply range - ±2V to ±18V dual-supply, 2.5V to 36V single-supply
- High slew rate - 325V/µs
- Fast settling - 80ns to 0.1% for a 10V step
- Low differential gain - 0.04% at A_V = +2, R_L = 150¾
- Low differential phase - 0.15° at A_V = +2, R_L = 150Ω
- Stable w/ unlimited capacitive load
- Wide output voltage swing - ±13.6V with V_S = ±15V, R_L = 1000Ω, 3.8V/0.3V with V_S = +5V, R_L = 500Ω
- Low cost, enhanced replacement for the AD827 andLT1229/LT1230

Applications

- Video amplifier
- Single-supply amplifier
- Active filters/integrators
- High-speed sample-and-hold
- High-speed signal processing
- ADC/DAC buffer
- Pulse/RF amplifier
- Pin diode receiver
- Log amplifier
- Photo multiplier amplifier
- Difference amplifier

Ordering Information

Part No.	Temp. Range	Package	Outline #
EL2244CN	-40°C to +85°C	8-Pin P-DIP	MDP0031
EL2244CS	-40°C to +85°C	8-Lead SO	MDP0027
EL2444CN	-40°C to +85°C	14-Pin P-DIP	MDP0031
EL2444CS	-40°C to +85°C	14-Lead SO	MDP0027
EL2444CM	-40°C to +85°C	16-Lead SOL	MDP0027

General Description

The EL2244C/EL2444C are dual and quad versions of the popular EL2044C. They are high speed, low power, low cost monolithic operational amplifiers built on Elantec's proprietary complementary bipolar process. The EL2244C/EL2444C are unity-gain stable and feature a 325V/µs slew rate and 120MHz gain-bandwidth product while requiring only 5.2mA of supply current per amplifier.

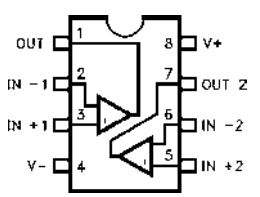
The power supply operating range of the EL2244C/EL2444C is from ±18V down to as little as ±2V. For single-supply operation, the EL2244C/EL2444C operate from 36V down to as little as 2.5V. The excellent power supply operating range of the EL2244C/EL2444C makes them an obvious choice for applications on a single +5V or +3V supply.

The EL2244C/EL2444C also feature an extremely wide output voltage swing of ±13.6V with V_S = ±15V and R_L = 1000Ω. At ±5V, output voltage swing is a wide ±3.8V with R_L = 500Ω and ±3.2V with R_L = 150Ω. Furthermore, for single-supply operation at +5V, output voltage swing is an excellent 0.3V to 3.8V with R_L = 500Ω.

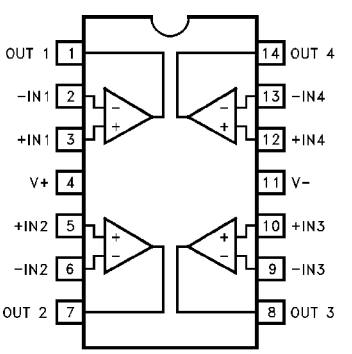
At a gain of +1, the EL2244C/EL2444C have a -3dB bandwidth of 120MHz with a phase margin of 50°. They can drive unlimited load capacitance, and because of their conventional voltage-feedback topology, the EL2244C/EL2444C allow the use of reactive or non-linear elements in their feedback network. This versatility combined with low cost and 75mA of output-current drive make the EL2244C/EL2444C an ideal choice for price-sensitive applications requiring low power and high speed.

Connection Diagrams

EL2244CN/CS
Dual



EL2444CN/CS
Quad



Note: All information contained in this data sheet has been carefully checked and is believed to be accurate as of the date of publication; however, this data sheet cannot be a "controlled document". Current revisions, if any, to these specifications are maintained at the factory and are available upon your request. We recommend checking the revision level before finalization of your design documentation.

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Absolute Maximum Ratings (T_A = 25 °C)

Supply Voltage (V_S)	±18V or 36V	Differential Input Voltage (dV_{IN})	±10V
Peak Output Current (I_{OP})	Short-Circuit Protected	Power Dissipation (P_D)	See Curves
Output Short-Circuit Duration	Infinite	Operating Temperature Range (T_A)	-40°C to +85°C
A heat-sink is required to keep junction temperature below absolute maximum when an output is shorted.		Operating Junction Temperature (T_J)	150°C
Input Voltage (V_{IN})	$\pm V_S$	Storage Temperature (T_{ST})	-65°C to +150°C

Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$.

DC Electrical Characteristics

V_S = ±15V, R_L = 1000Ω, unless otherwise specified

Parameter	Description	Condition	Temp	Min	Typ	Max	Unit
V_{OS}	Input Offset Voltage	V_S = ±15V	25°C		0.5	4.0	mV
			T_{MIN}, T_{MAX}			9.0	mV
TCV_{OS}	Average Offset Voltage Drift	[1]	All		10.0		µV/°C
I_B	Input Bias Current	V_S = ±15V	25°C		2.8	8.2	µA
			T_{MIN}, T_{MAX}			11.2	µA
		V_S = ±5V	25°C		2.8		µA
I_{OS}	Input Offset Current	V_S = ±15V	25°C		50	300	nA
			T_{MIN}, T_{MAX}			500	nA
		V_S = ±5V	25°C		50		nA
TCI_{OS}	Average Offset Current Drift	[1]	All		0.3		nA/°C
A_{VOL}	Open-Loop Gain	V_S = ±15V,V_{OUT} = ±10V, R_L = 1000Ω	25°C	800	1500		V/V
			T_{MIN}, T_{MAX}	600			V/V
		V_S = ±5V, V_{OUT} = ±2.5V, R_L = 500Ω	25°C		1200		V/V
		V_S = ±5V, V_{OUT} = ±2.5V, R_L = 150Ω	25°C		1000		V/V
PSRR	Power Supply Rejection Ratio	V_S = ±5V to ±15V	25°C	65	80		dB
			T_{MIN}, T_{MAX}	60			dB
CMRR	Common-Mode Rejection Ratio	V_{CM} = ±12V, V_{OUT} = 0V	25°C	70	90		dB
			T_{MIN}, T_{MAX}	70			dB
CMIR	Common-Mode Input Range	V_S = ±15V	25°C		±14.0		V
		V_S = ±5V	25°C		±4.2		V
		V_S = +5V	25°C		4.2/0.1		V
V_{OUT}	Output Voltage Swing	V_S = ±15V, R_L = 1000Ω	25°C	±13.4	±13.6		V
			T_{MIN}, T_{MAX}	±13.1			V
		V_S = ±15V, R_L = 500Ω	25°C	±12.0	±13.4		V
		V_S = ±5V, R_L = 500Ω	25°C	±3.4	±3.8		V
		V_S = ±5V, R_L = 150Ω	25°C		±3.2		V
		V_S = +5V, R_L = 500Ω	25°C	3.6/0.4	3.8/0.3		V
			T_{MIN}, T_{MAX}	3.5/0.5			V
I_{SC}	Output Short Circuit Current		25°C	40	75		mA
			T_{MIN}, T_{MAX}	35			mA
I_S	Supply Current (Per Amplifier)	V_S = ±15V, No Load	25°C		5.2	7	mA
			T_{MIN}			7.6	mA
			T_{MAX}			7.6	mA
		V_S = ±5V, No Load	25°C		5.0		mA

DC Electrical Characteristics (Continued)

V_S = ±15V, R_L = 1000Ω, unless otherwise specified

Parameter	Description	Condition	Temp	Min	Typ	Max	Unit
R_{IN}	Input Resistance	Differential	25°C		150		kΩ
		Common-Mode	25°C		15		MΩ
C_{IN}	Input Capacitance	A_V = +1@ 10MHz	25°C		1.0		pF
R_{OUT}	Output Resistance	A_V = +1	25°C		50		mΩ
PSOR	Power-Supply Operating Range	Dual-Supply	25°C	±2.0		±18.0	V
		Single-Supply	25°C	2.5		36.0	V

1. Measured from T_{MIN} to T_{MAX}.

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Closed-Loop AC Electrical Characteristics

V_S = ±15V, A_V = +1, R_L = 1000Ω unless otherwise specified

Parameter	Description	Condition	Temp	Min	Typ	Max	Unit
BW	-3dB Bandwidth (V_{OUT} = 0.4V_{PP})	V_S = ±15V, A_V = +1	25°C		120		MHz
		V_S = ±15V, A_V = -1	25°C		60		MHz
		V_S = ±15V, A_V = +2	25°C		60		MHz
		V_S = ±15V, A_V = +5	25°C		12		MHz
		V_S = ±15V, A_V = +10	25°C		6		MHz
		V_S = ±5V, A_V = +1	25°C		80		MHz
GBWP	Gain-Bandwidth Product	V_S = ±15V	25°C		60		MHz
		V_S = ±5V	25°C		45		MHz
PM	Phase Margin	R_L = 1 k¾, C_L = 10pF	25°C		50		°
CS	Channel Separation	f = 5MHz	25°C		85		dB
SR	Slew Rate [1]	V_S = ±15V, R_L = 1000Ω	25°C	250	325		V/µs
		V_S = ±5V, R_L = 500Ω	25°C		200		V/µs
FPBW	Full-Power Bandwidth [2]	V_S = ±15V	25°C	4.0	5.2		MHz
		V_S = ±5V	25°C		12.7		MHz
t_r, t_f	Rise Time, Fall Time	0.1V Step	25°C		3.0		ns
OS	Overshoot	0.1V Step	25°C		20		%
t_{PD}	Propagation Delay		25°C		2.5		ns
t_s	Settling to +0.1% (A_V = +1)	V_S = ±15V, 10V Step	25°C		80		ns
		V_S = ±5V, 5V Step	25°C		60		ns
dG	Differential Gain [3]	NTSC/PAL	25°C		0.04		%
dP	Differential Phase [3]	NTSC/PAL	25°C		0.15		°
eN	Input Noise Voltage	10kHz	25°C		15.0		nV√Hz
iN	Input Noise Current	10kHz	25°C		1.50		pA√Hz
CI STAB	Load Capacitance Stability	A_V = +1	25°C		Infinite		pF

1. Slew rate is measured on rising edge
2. For V_S = ±15V, V_{OUT} = 20V_{PP}. For V_S = ±5V, V_{OUT} = 5V_{PP}. Full-power bandwidth is based on slew rate measurement using: FPBW = SR/(2π * Vpeak).
3. Video Performance measured at V_S = ±15V, A_V = +2 with 2 times normal video level across R_L = 150Ω. This corresponds to standard video levels across a back-terminated 75Ω load. For other values of R_L, see curves.

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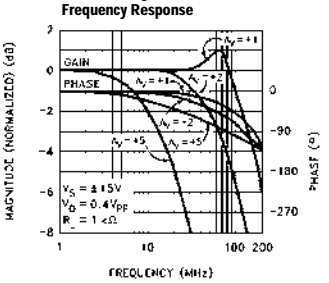
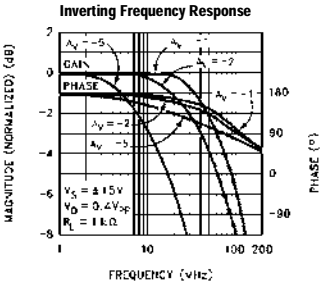
Typical Performance Curves

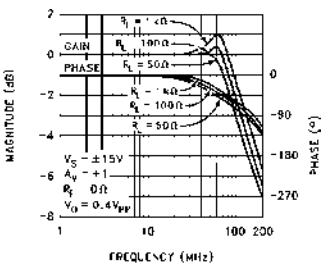
Non-Inverting Frequency Response



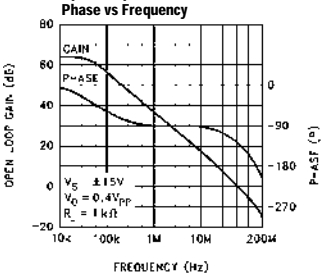
Inverting Frequency Response



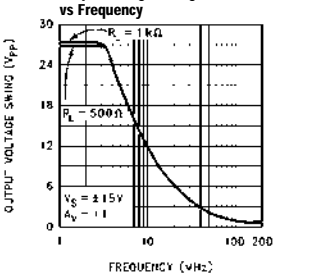
Frequency Response for Various Load Resistances



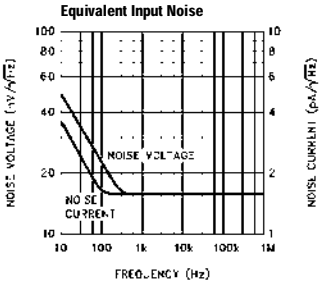
Open-Loop Gain and Phase vs Frequency



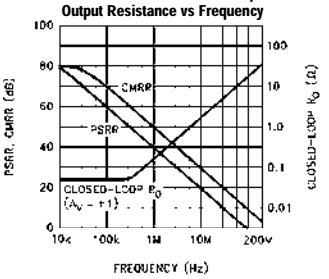
Output Voltage Swing vs Frequency



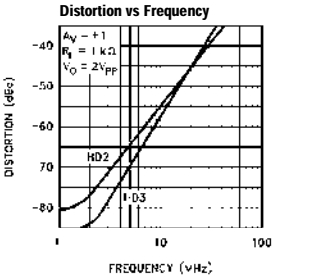
Equivalent Input Noise



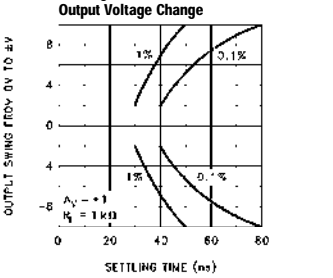
CMRR, PSRR and Closed-Loop Output Resistance vs Frequency



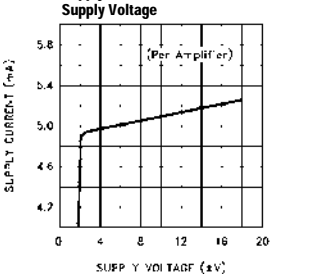
2nd and 3rd Harmonic Distortion vs Frequency



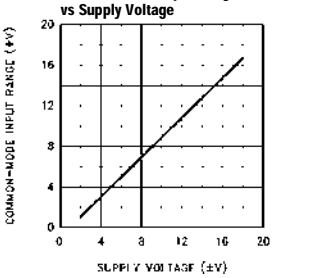
Settling Time vs Output Voltage Change



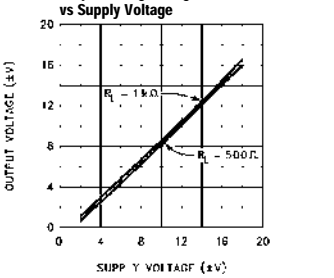
Supply Current vs Supply Voltage



Common-Mode Input Range vs Supply Voltage



Output Voltage Range vs Supply Voltage



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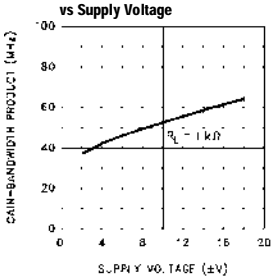
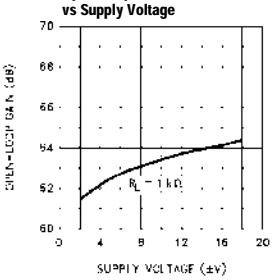
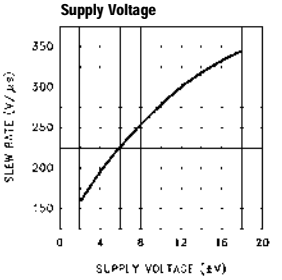
Gain-Bandwidth Product vs Supply Voltage



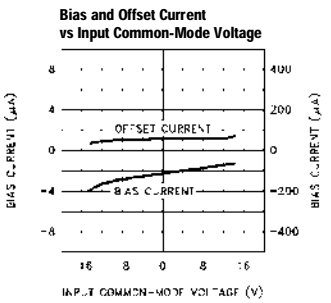
Open-Loop Gain vs Supply Voltage



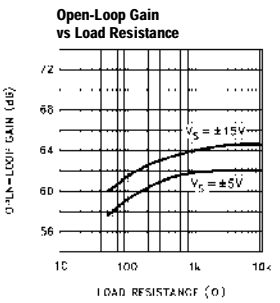
Slew-Rate vs Supply Voltage



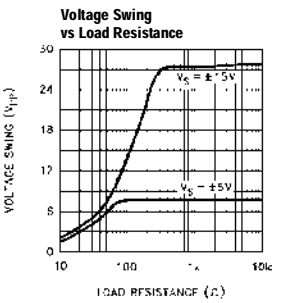
Bias and Offset Current vs Input Common-Mode Voltage



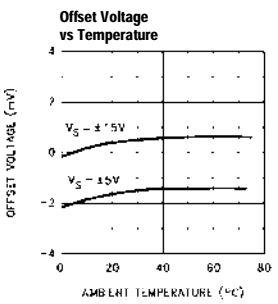
Open-Loop Gain vs Load Resistance



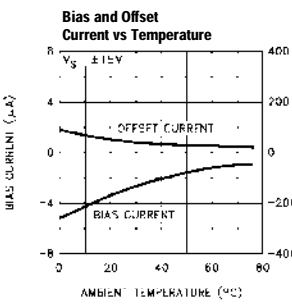
Voltage Swing vs Load Resistance



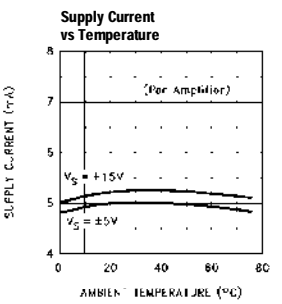
Offset Voltage vs Temperature



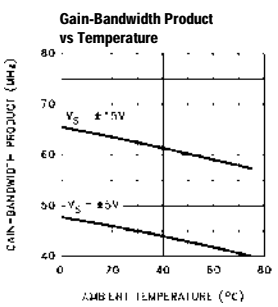
Bias and Offset Current vs Temperature



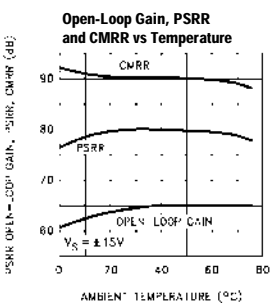
Supply Current vs Temperature



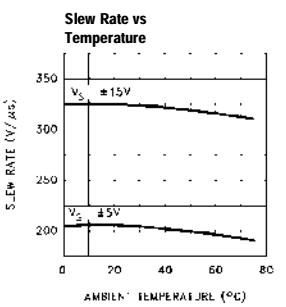
Gain-Bandwidth Product vs Temperature



Open-Loop Gain, PSRR and CMRR vs Temperature



Slew Rate vs Temperature



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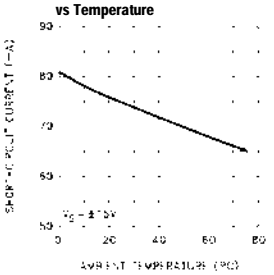
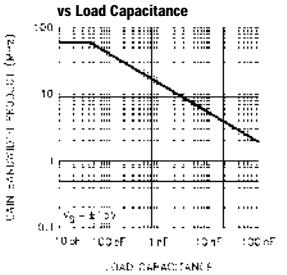
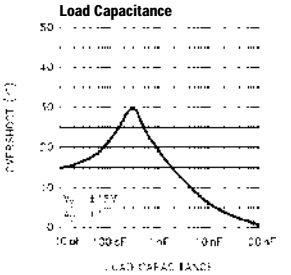
Short-Circuit Current vs Temperature



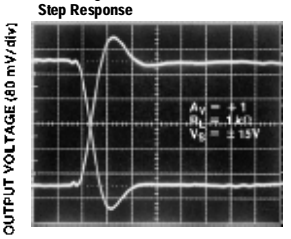
Gain-Bandwidth Product vs Load Capacitance



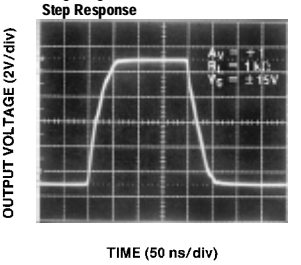
Overshoot vs Load Capacitance



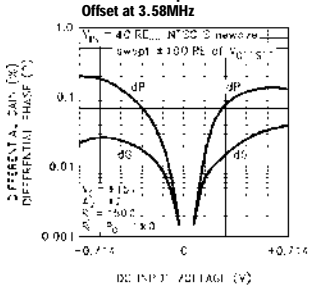
Small-Signal Step Response



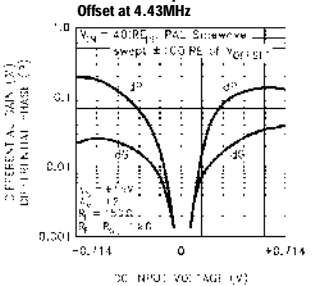
Large-Signal Step Response



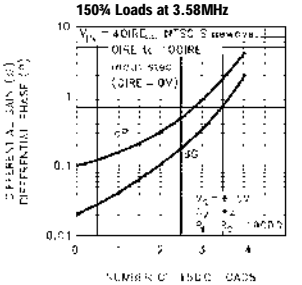
Differential Gain and Phase vs DC Input Offset at 3.58MHz



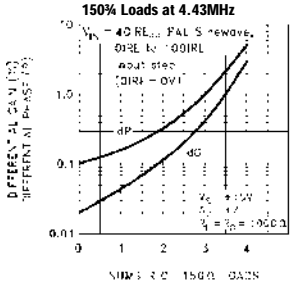
Differential Gain and Phase vs DC Input Offset at 4.43MHz



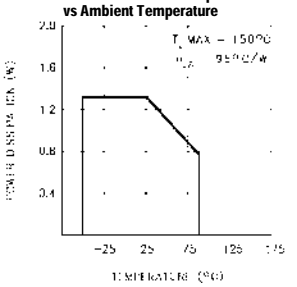
Differential Gain and Phase vs Number of 150¾ Loads at 3.58MHz



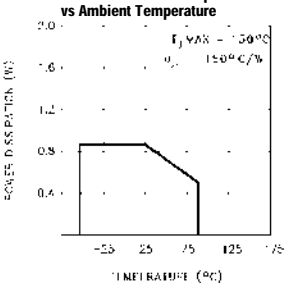
Differential Gain and Phase vs Number of 150¾ Loads at 4.43MHz



8-Pin Plastic DIP Maximum Power Dissipation vs Ambient Temperature



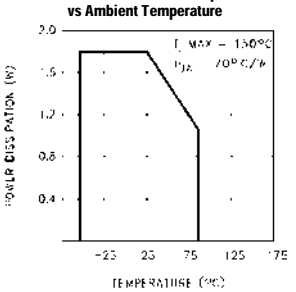
8-Lead SO Maximum Power Dissipation vs Ambient Temperature



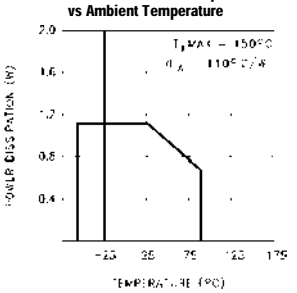
EL2244C, EL2444C

Dual/Quad Low-Power 120MHz Unity-Gain Stable Op Amp

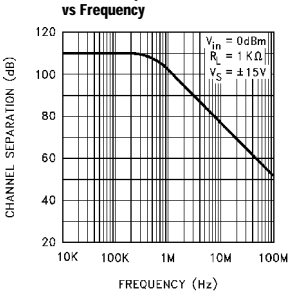
14-Pin Plastic DIP
Maximum Power Dissipation
vs Ambient Temperature



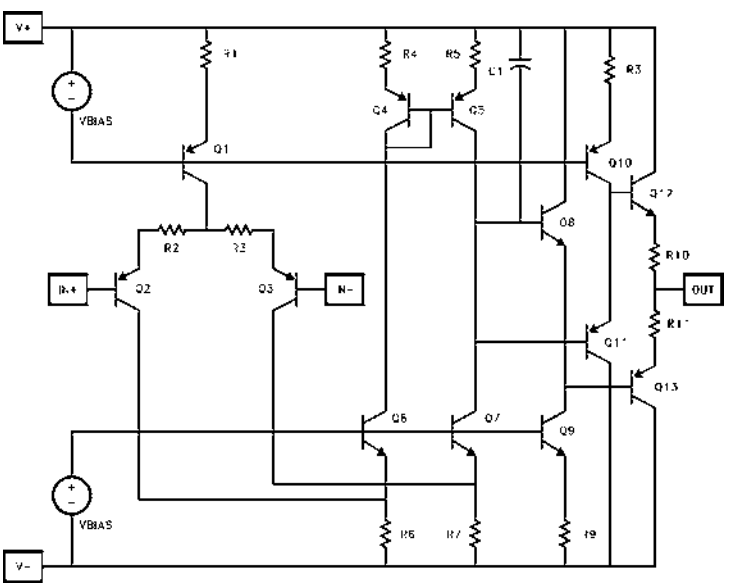
14-Lead SO
Maximum Power Dissipation
vs Ambient Temperature



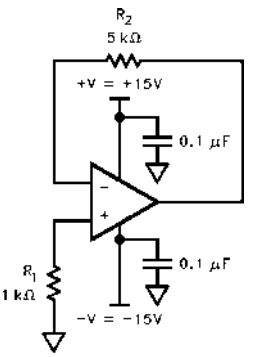
Channel Separation
vs Frequency



Simplified Schematic (Per Amplifier)



Burn-In Circuit (Per Amplifier)



All Packages Use the Same Schematic

EL2244C, EL2444C

Dual/Quad Low-Power 120MHz Unity-Gain Stable Op Amp

Applications Information

Product Description

The EL2244C/EL2444C are low-power wideband monolithic operational amplifiers built on Elantec's proprietary high-speed complementary bipolar process. The EL2244C/EL2444C use a classical voltage-feedback topology which allows them to be used in a variety of applications where current-feedback amplifiers are not appropriate because of restrictions placed upon the feedback element used with the amplifier. The conventional topology of the EL2244C/EL2444C allows, for example, a capacitor to be placed in the feedback path, making it an excellent choice for applications such as active filters, sample-and-holds, or integrators. Similarly, because of the ability to use diodes in the feedback network, the EL2244C/EL2444C are an excellent choice for applications such as fast log amplifiers.

Power Dissipation

With the wide power supply range and large output drive capability of the EL2244C/EL2444C, it is possible to exceed the 150°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature (T_{Jmax}) for all applications to determine if power supply voltages, load conditions, or package type need to be modified for the EL2244C/EL2444C to remain in the safe operating area. These parameters are related as follows:

$T_{Jmax} = T_{max} + (\theta_{JA} * (PDmaxtotal))$

where PDmaxtotal is the sum of the maximum power dissipation of each amplifier in the package (PDmax). PDmax for each amplifier can be calculated as follows:

$PDmax = (2*V_S*I_{Smax}+(V_S-V_{outmax})*(V_{outmax}/R_L))$

where:

T_{max} =Maximum Ambient Temperature

θ_{JA} =Thermal Resistance of the Package

PDmax =Maximum Power Dissipation of 1 Amplifier

V_S =Supply Voltage

I_{Smax} =Maximum Supply Current of 1 Amplifier

V_{outmax}=Maximum Output Voltage Swing of the Application

R_L =Load Resistance

To serve as a guide for the user, we can calculate maximum allowable supply voltages for the example of the video cable-driver below since we know that T_{Jmax} = 150°C, T_{max} = 75°C, I_{Smax} = 7.6mA, and the package θ_{JA}s are shown in Table 1. If we assume (for this example) that we are driving a back-terminated video cable, then the maximum average value (over duty-cycle) of V_{outmax} is 1.4V, and R_L = 150¾, giving the results seen in Table 1.

Table 1

Duals	Package	θ_{JA}	Max PDiss @ T_{max}	Max V_S
EL2244CN	PDIP8	95°C/W	0.789W @ 75°C	±16.6V
EL2244CS	SO8	150°C/W	0.500W @ 75°C	±10.7V
QUADS				
EL2444CN	PDIP14	70°C/W	1.071W @ 75°C	±11.5V
EL2444CS	SO14	110°C/W	0.682W @ 75°C	±7.5V

Single-Supply Operation

The EL2244C/EL2444C have been designed to have a wide input and output voltage range. This design also makes the EL2244C/EL2444C an excellent choice for single-supply operation. Using a single positive supply, the lower input voltage range is within 100mV of ground (R_L = 500Ω), and the lower output voltage range is within 300 mV of ground. Upper input voltage range reaches 4.2V, and output voltage range reaches 3.8V with a 5V supply and R_L = 500Ω. This results in a 3.5V output swing on a single 5V supply. This wide output voltage range also allows single-supply operation with a supply voltage as high as 36V or as low as 2.5V. On a single 2.5V supply, the EL2244C/EL2444C still have 1V of output swing.

Gain-Bandwidth Product and the-3dB Bandwidth

The EL2244C/EL2444C have a gain-bandwidth product of 120 MHz while using only 5.2mA of supply current per amplifier. For gains greater than 4, their closed-loop -3 dB bandwidth is approximately equal to the gain-

bandwidth product divided by the noise gain of the circuit. For gains less than 4, higher-order poles in the amplifiers' transfer function contribute to even higher closed loop bandwidths. For example, the EL2244C/EL2444C have a -3dB bandwidth of 120MHz at a gain of +1, dropping to 60MHz at a gain of +2. It is important to note that the EL2244C/EL2444C have been designed so that this "extra" bandwidth in low-gain applications does not come at the expense of stability. As seen in the typical performance curves, the EL2244C/EL2444C in a gain of +1 only exhibit 1.0dB of peaking with a 1000Ω load.

Video Performance

An industry-standard method of measuring the video distortion of components such as the EL2244C/EL2444C is to measure the amount of differential gain (dG) and differential phase (dP) that they introduce. To make these measurements, a 0.286V_{PP} (40 IRE) signal is applied to the device with 0V DC offset (0 IRE) at either 3.58MHz for NTSC or 4.43MHz for PAL. A second measurement is then made at 0.714V DC offset (100 IRE). Differential gain is a measure of the change in amplitude of the sine wave, and is measured in percent. Differential phase is a measure of the change in phase, and is measured in degrees.

For signal transmission and distribution, a back-terminated cable (75Ω in series at the drive end, and 75Ω to ground at the receiving end) is preferred since the impedance match at both ends will absorb any reflections. However, when double termination is used, the received signal is halved; therefore a gain of 2 configuration is typically used to compensate for the attenuation.

The EL2244C/EL2444C have been designed as an economical solution for applications requiring low video distortion. They have been thoroughly characterized for video performance in the topology described above, and the results have been included as typical dG and dP specifications and as typical performance curves. In a gain of +2, driving 150Ω, with standard video test levels at the input, the EL2244C/EL2444C exhibit dG and dP of only 0.04% and 0.15° at NTSC and PAL. Because dG and dP can vary with different DC offsets, the video performance of the EL2244C/EL2444C has been characterized over the entire DC offset range from -0.714V to +0.714V. For more information, refer to the curves of dG and dP vs DC Input Offset.

Output Drive Capability

The EL2244C/EL2444C have been designed to drive low impedance loads. They can easily drive 6V_{PP} into a 150¾ load. This high output drive capability makes the EL2244C/EL2444C an ideal choice for RF, IF and video applications. Furthermore, the current drive of the EL2244C/EL2444C remains a minimum of 35 mA at low temperatures. The EL2244C/EL2444C are current-limited at the output, allowing it to withstand shorts to ground. However, power dissipation with the output shorted can be in excess of the power-dissipation capabilities of the package.

Capacitive Loads

For ease of use, the EL2244C/EL2444C have been designed to drive any capacitive load. However, the EL2244C/EL2444C remain stable by automatically reducing their gain-bandwidth product as capacitive load increases. Therefore, for maximum bandwidth, capacitive loads should be reduced as much as possible or isolated via a series output resistor (Rs). Similarly, coax lines can be driven, but best AC performance is obtained when they are terminated with their characteristic impedance so that the capacitance of the coaxial cable will not add to the capacitive load seen by the amplifier. Although stable with all capacitive loads, some peaking still occurs as load capacitance increases. A series resistor at the output of the EL2244C/EL2444C can be used to reduce this peaking and further improve stability.

Printed-Circuit Layout

The EL2244C/EL2444C are well behaved, and easy to apply in most applications. However, a few simple techniques will help assure rapid, high quality results. As with any high-frequency device, good PCB layout is necessary for optimum performance. Ground-plane construction is highly recommended, as is good power supply bypassing. A 0.1 µF ceramic capacitor is recommended for bypassing both supplies. Lead lengths should be as short as possible, and bypass capacitors should be as close to the device pins as possible. For

good AC performance, parasitic capacitances should be kept to a minimum at both inputs and at the output. Resistor values should be kept under 5 kΩ because of the RC time constants associated with the parasitic capacitance. Metal-film and carbon resistors are both acceptable, use of wire-wound resistors is not recommended because of their parasitic inductance. Similarly, capacitors should be low-inductance for best performance.

The EL2244C/EL2444C Macromodel

This macromodel has been developed to assist the user in simulating the EL2244C/EL2444C with surrounding circuitry. It has been developed for the PSPICE simulator (copywritten by the Microsim Corporation), and may need to be rearranged for other simulators. It approximates DC, AC, and transient response for resistive loads, but does not accurately model capacitive loading. This model is slightly more complicated than the models used for low-frequency op-amps, but it is much more accurate for AC analysis.

The model does not simulate these characteristics accurately:

noise	non-linearities
settling-time	temperature effects
CMRR	manufacturing variations
PSRR	

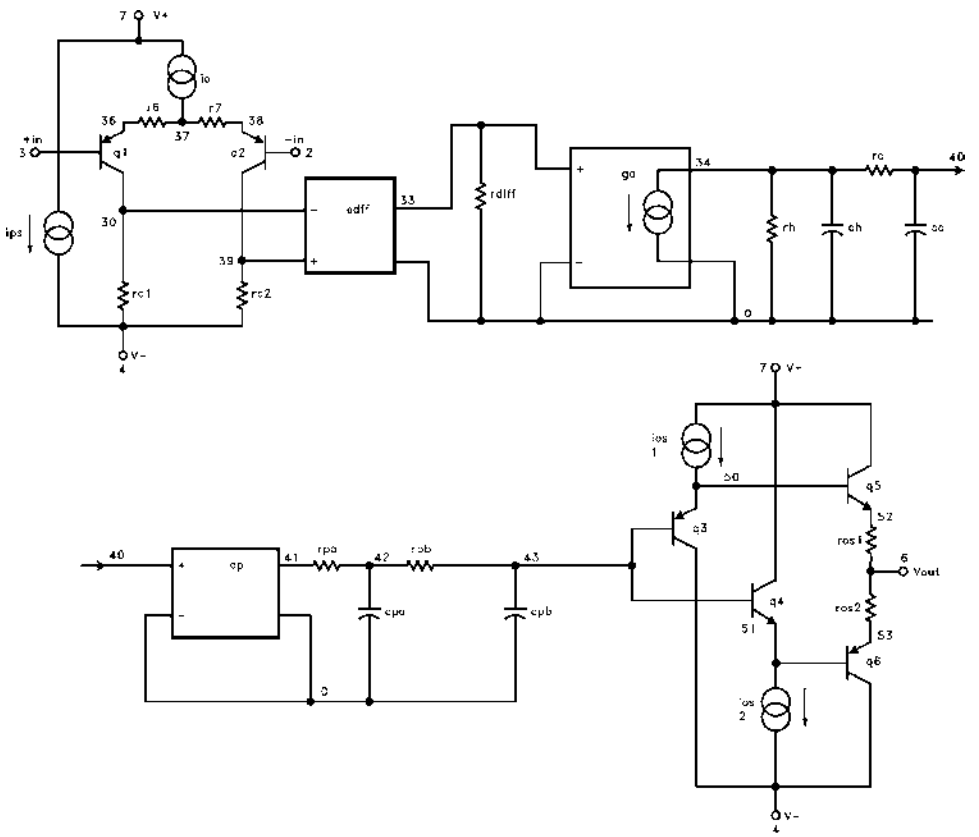
EL2244C/EL2444 Macromodel

```
* Connections:  +input
*               |    -input
*               |    |    +Vsupply
*               |    |    |    -Vsupply
*               |    |    |    |    output
*               |    |    |    |    |
.subckt M2244   3    2    7    4    6
*
* Input stage
*
ie 7 37 1mA
r6 36 37 800
r7 38 37 800
rc1 4 30 850
rc2 4 39 850
q1 30 3 36 qp
q2 39 2 38 qpa
ediff 33 0 39 30 1.0
rdiff 33 0 1Meg
*
* Compensation Section
*
ga 0 34 33 0 1m
rh 34 0 2Meg
ch 34 0 1.3pF
rc 34 40 1K
cc 40 0 1pF
*
* Poles
*
ep 41 0 40 0 1
rpa 41 42 200
cpa 42 0 1pF
rpb 42 43 200
cpb 43 0 1pF
*
* Output Stage
*
ios1 7 50 1.0mA
ios2 51 4 1.0mA
q3 4 43 50 qp
q4 7 43 51 qn
q5 7 50 52 qn
q6 4 51 53 qp
ros1 52 6 25
ros2 6 53 25
*
* Power Supply Current
*
ips 7 4 2.7mA
*
* Models
*
.model qn npn(is=800E-18 bf=200 tf=0.2nS)
.model qpa pnp(is=864E-18 bf=100 tf=0.2nS)
.model qp pnp(is=800E-18 bf=125 tf=0.2nS)
.ends
```

EL2244C, EL2444C

Dual/Quad Low-Power 120MHz Unity-Gain Stable Op Amp

EL2244C/EL2444C Macromodel



EL2244C/EL2444C Model

EL2244C, EL2444C

EL2244C, EL2444C

Dual/Quad Low-Power 120MHz Unity-Gain Stable Op Amp

General Disclaimer

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HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

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